NEC

Solid State Relay
OCMOS FET

PS7522-1A,-2A,PS7522L-1A,-2A

6, 8-PIN DIP, SLOW SWITCHING TYPE
1-ch, 2-ch Optical Coupled MOS FET

DESCRIPTION

The PS7522-1A, -2A and PS7522L-1A, -2A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for equipments which are necessary to prevent some noise, because of their slow switching speed at turn-on or turn-off.

The PS7522L-1A, -2A have a surface mount type lead.

★ FEATURES

- 1 channel type (1 a output) or 2 channel type (1 a + 1 a output)
- Low LED operating current (I_F = 1 mA)
- Designed for AC/DC switching line changer
- Small package (6, 8-pin DIP)
- Slow turn-on time, slow turn-off time (t_{on} = 12 ms MAX., t_{off} = 6.5 ms MAX.)
- Low offset voltage
- PS7522L-1A, -2A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8245/8246
- CSA approved: No. CA 101391

APPLICATIONS

- Exchange equipment
- Measurement equipment
- FA/OA equipment

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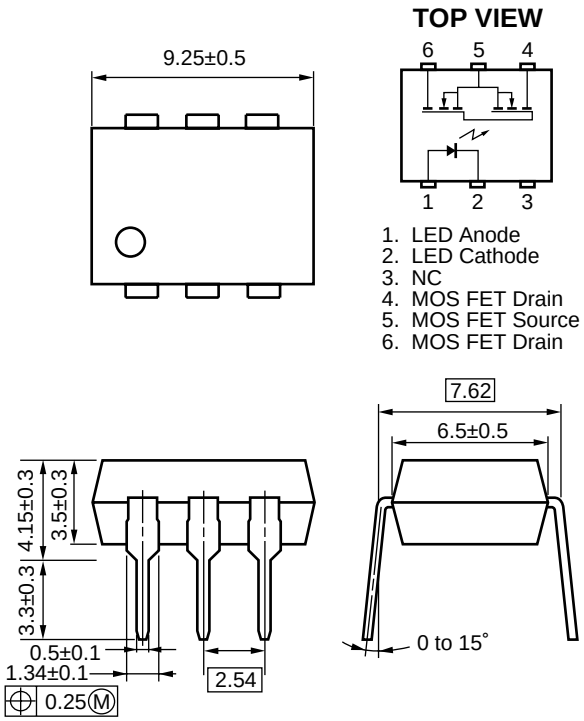
Printed in Japan

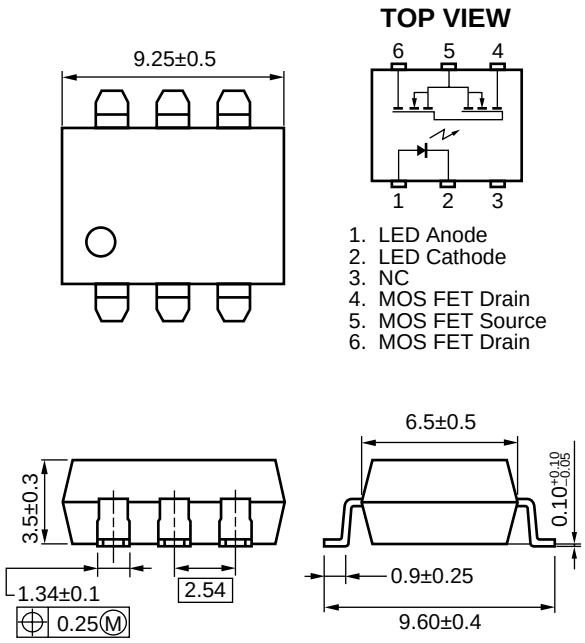
The mark ★ shows major revised points.

PACKAGE DIMENSIONS (in millimeters)

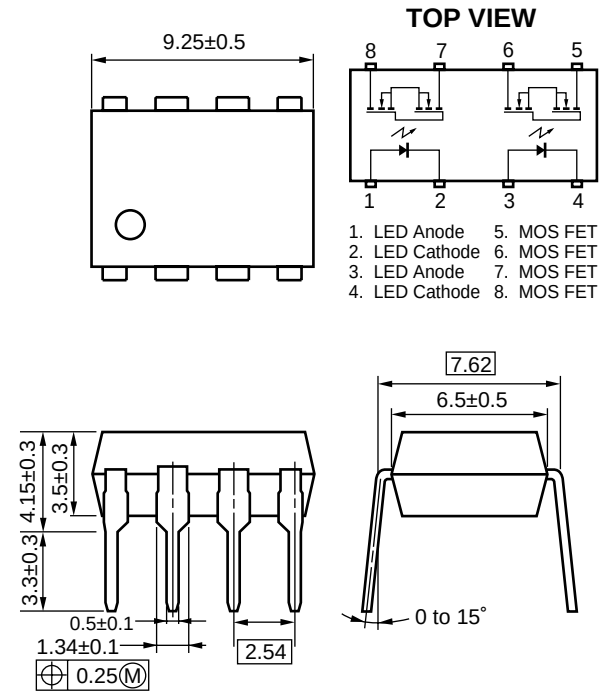
PS7522-1A



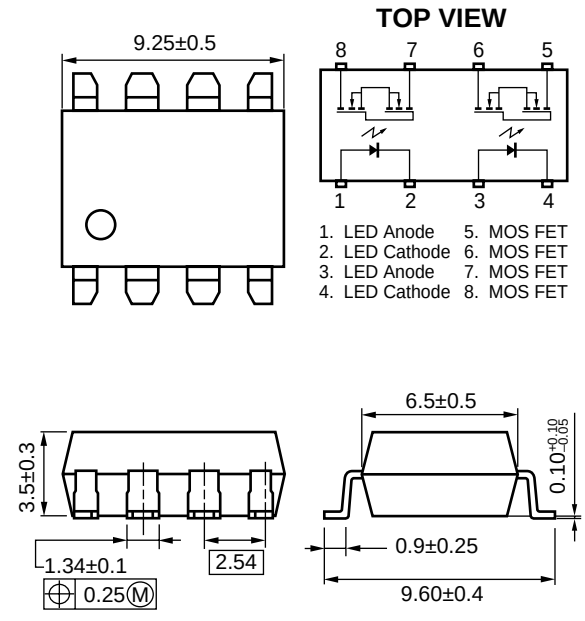
PS7522L-1A



PS7522-2A



PS7522L-2A



★ ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number[*1]
PS7522-1A	6-pin DIP	Magazine case 50 pcs	PS7522-1A
PS7522L-1A			PS7522L-1A
PS7522L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7522L-1A-E4			
PS7522-2A	8-pin DIP	Magazine case 50 pcs	PS7522-2A
PS7522L-2A			PS7522L-2A
PS7522L-2A-E3		Embossed Tape 1 000 pcs/reel	
PS7522L-2A-E4			

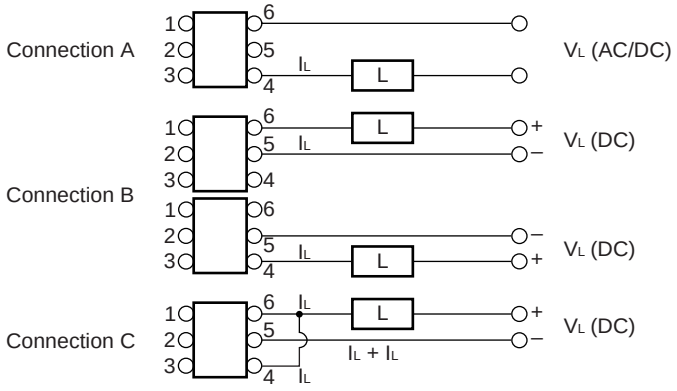
***1** For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

Parameter			Symbol	Ratings		Unit
				PS7522-1A, PS7522L-1A	PS7522-2A, PS7522L-2A	
Diode	Forward Current (DC)		I_F	50		mA
	Reverse Voltage		V_R	5.0		V
	Power Dissipation		P_D	50		mW/ch
	Peak Forward Current *1		I_{FP}	1		A
MOS FET	Break Down Voltage		V_L	200		V
★	Continuous Load Current *2	Connection A	I_L	200		mA
		Connection B		350	–	
		Connection C		400	–	
★	Pulse Load Current *3 (AC/DC Connection)		I_{LP}	400		mA
	Power Dissipation		P_D	560	375	mW/ch
Isolation Voltage *4			BV	1 500		Vr.m.s.
Total Power Dissipation			P_T	610	850	mW
Operating Ambient Temperature			T_A	–40 to +80		°C
Storage Temperature			T_{stg}	–40 to +100		°C

***1** PW = 100 μs, Duty Cycle = 1 %

***2** Conditions: $I_F \geq 2$ mA. The following types of load connections are available.



***3** PW = 100 ms, 1 shot

***4** AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output

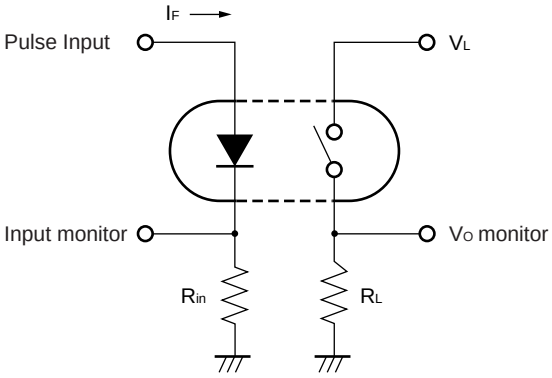
RECOMMENDED OPERATING CONDITIONS (T_A = 25 °C)

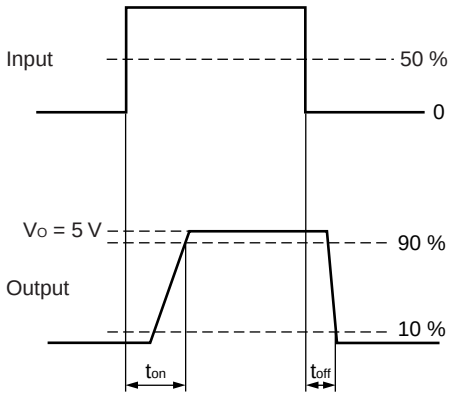
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	I_F	1	10	20	mA
LED Off Voltage	V_F	0		0.5	V

★ ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V_F	I_F = 1.4 mA		1.1	1.4	V
	Reverse Current	I_R	V_R = 5 V			5.0	μA
MOS FET	Off-state Leakage Current	I_{Loff}	V_D = 200 V		0.03	1.0	μA
	Output Capacitance	C_{out}	V_D = 0 V, f = 1 MHz		165		pF/ch
Coupled	LED On-state Current	I_{Fon}	I_L = 200 mA			1.0	mA
	On-state Resistance	R_{on1}	I_F = 1.4 mA, I_L = 10 mA		3.0	5.0	Ω
		R_{on2}	I_F = 10 mA, I_L = 200 mA, t ≤ 20 ms				
	Turn-on Time *1	t_{on}	I_F = 1.4 mA, V_O = 60 V, PW ≥ 50 ms		8.5	12	ms
	Rise Time	t_r		0.80	2.78		
	Turn-off Time *1	t_{off}			3.0	6.5	
	Fall Time	t_f		0.4	0.8		
	Isolation Resistance	R_{I-O}	V_{I-O} = 1.0 kV_{DC}	10^9			Ω
	Isolation Capacitance	C_{I-O}	V = 0 V, f = 1 MHz		1.1		pF/ch

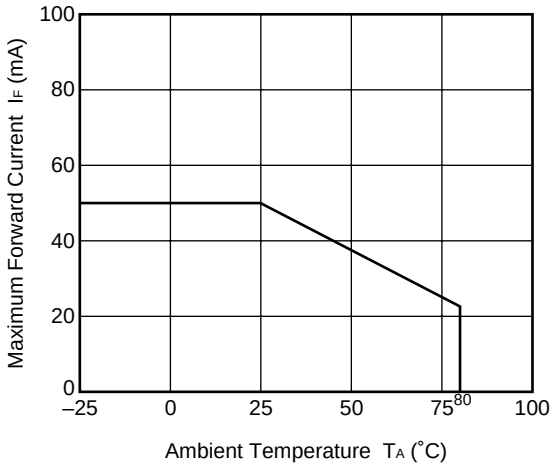
***1** Test Circuit for Switching Time



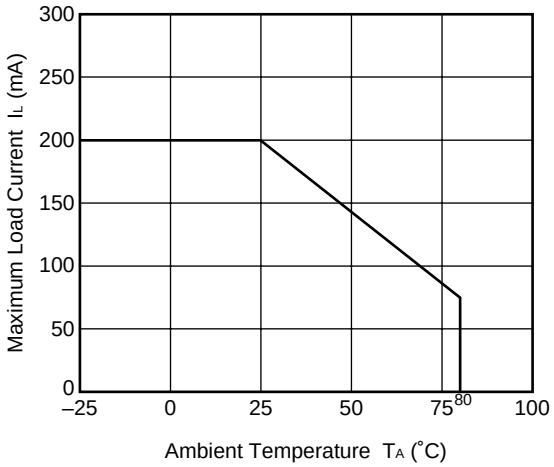


★ **TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)**

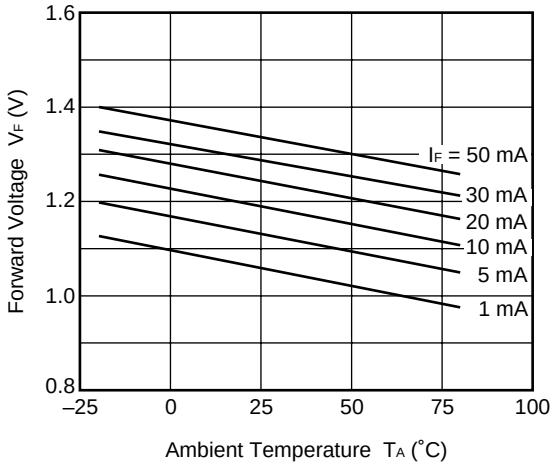
MAXIMUM FORWARD CURRENT vs. AMBIENT TEMPERATURE



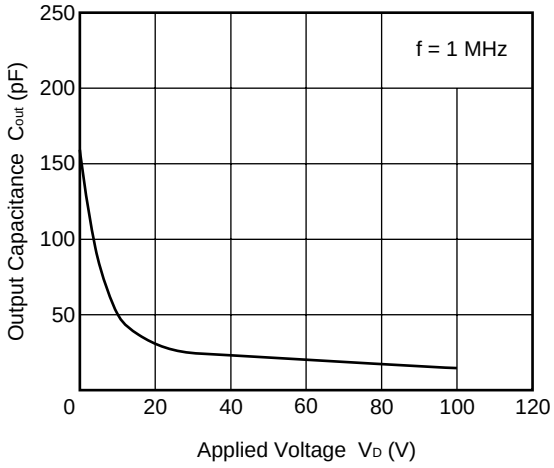
MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE



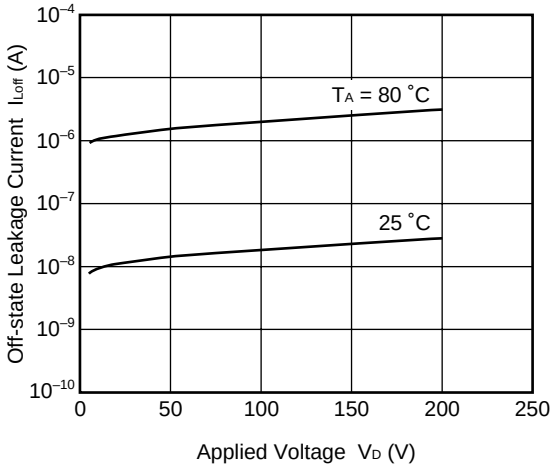
FORWARD VOLTAGE vs. AMBIENT TEMPERATURE



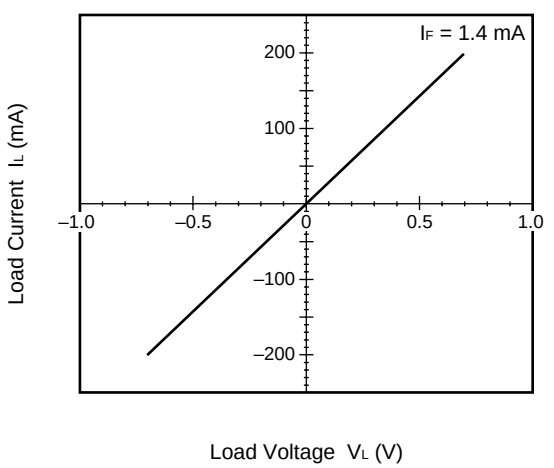
OUTPUT CAPACITANCE vs. APPLIED VOLTAGE



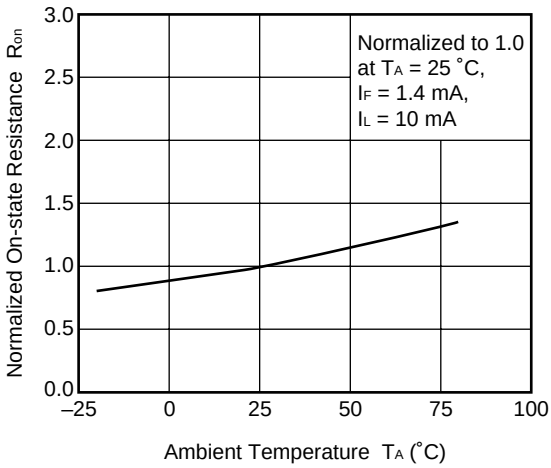
OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE



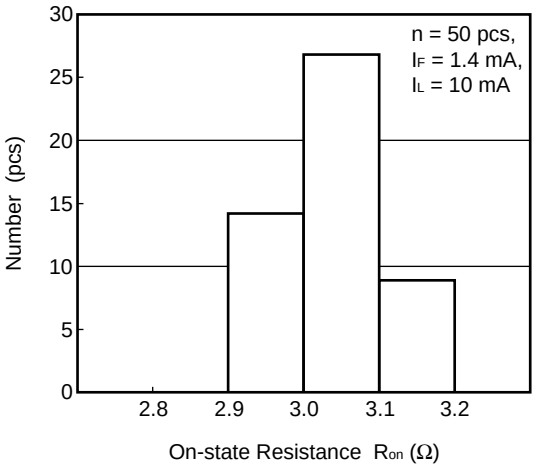
LOAD CURRENT vs. LOAD VOLTAGE



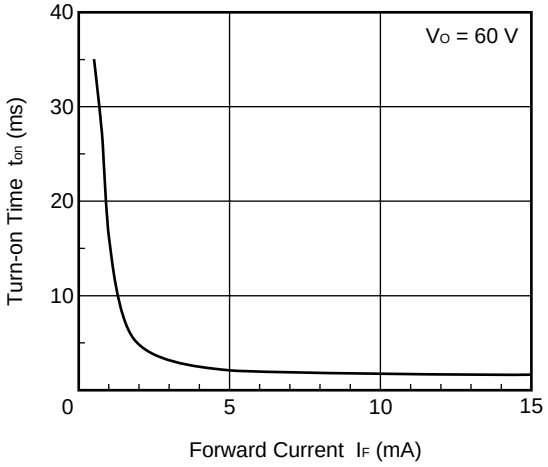
NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



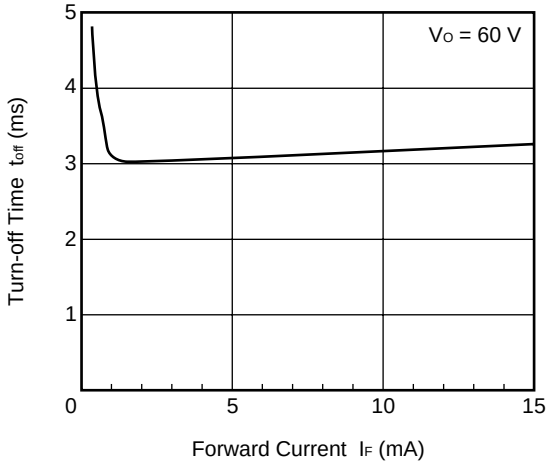
ON-STATE RESISTANCE DISTRIBUTION



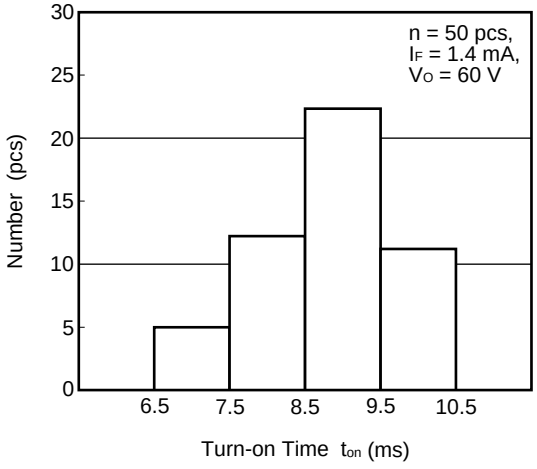
TURN-ON TIME vs. FORWARD CURRENT



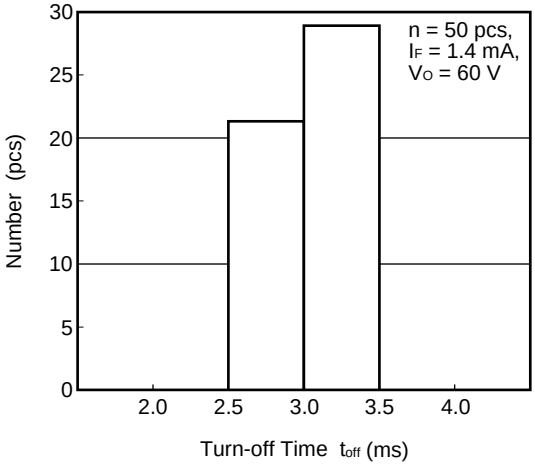
TURN-OFF TIME vs. FORWARD CURRENT



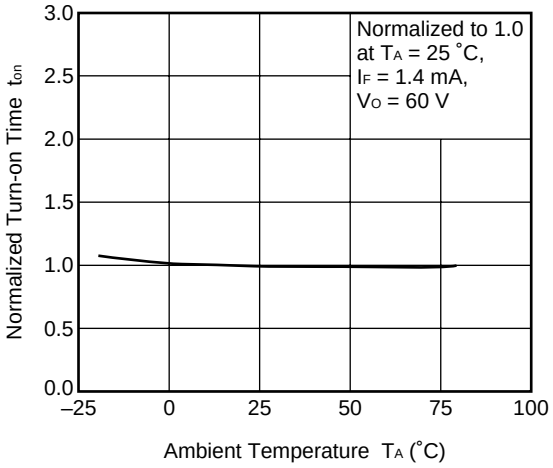
TURN-ON TIME DISTRIBUTION



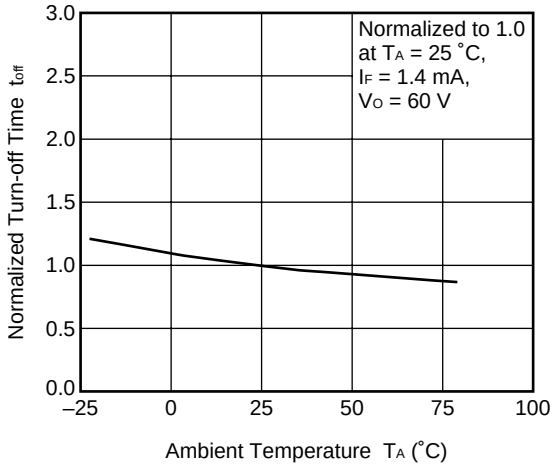
TURN-OFF TIME DISTRIBUTION



NORMALIZED TURN-ON TIME vs.
AMBIENT TEMPERATURE



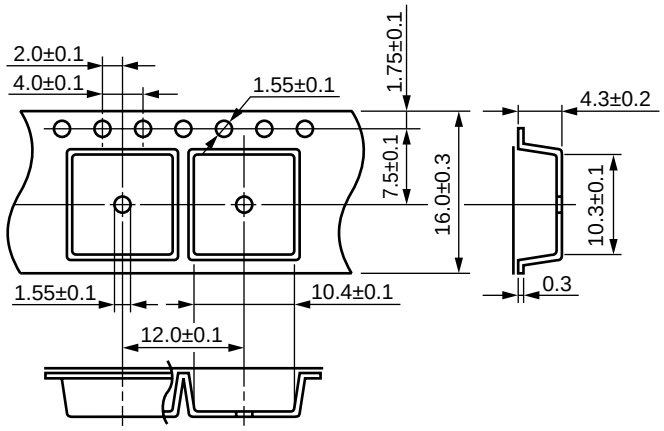
NORMALIZED TURN-OFF TIME vs.
AMBIENT TEMPERATURE



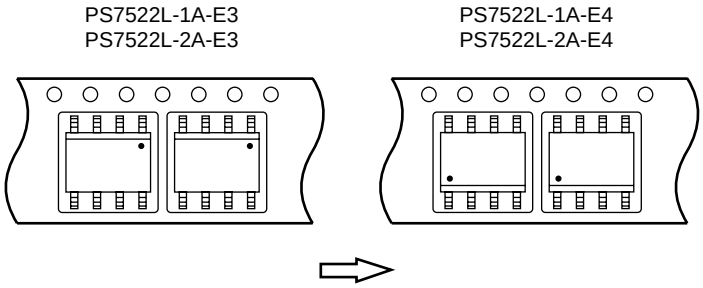
Remark The graphs indicate nominal characteristics.

★ **TAPING SPECIFICATIONS (in millimeters)**

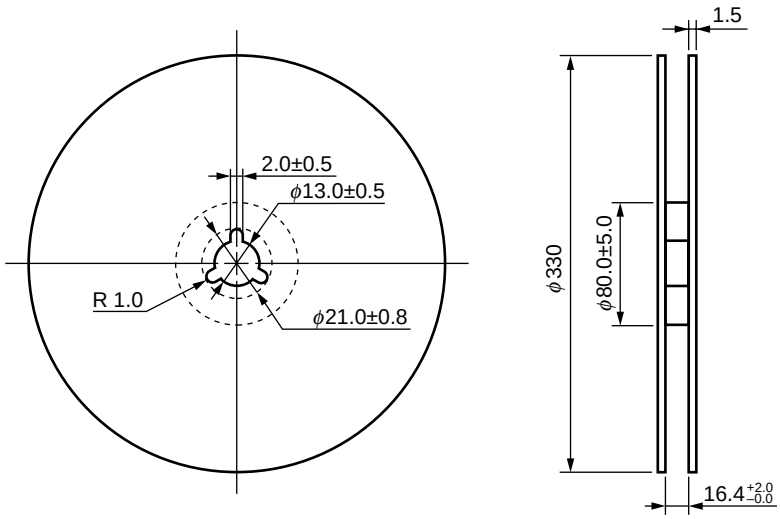
Outline and Dimensions (Tape)



Tape Direction



Outline and Dimensions (Reel)



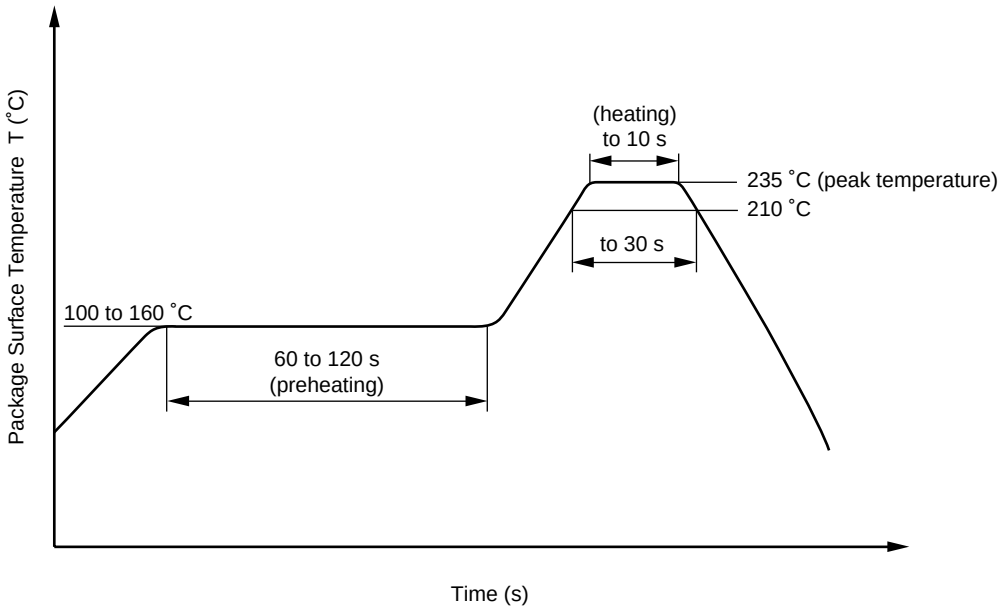
Packing: 1 000 pcs/reel

RECOMMENDED SOLDERING CONDITIONS

(1) Infrared reflow soldering

- Peak reflow temperature — 235 °C (package surface temperature)
- Time of temperature higher than 210 °C — 30 seconds or less
- Number of reflows — Two
- Flux — Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

★ Recommended Temperature Profile of Infrared Reflow



(2) Dip soldering

- Temperature — 260 °C or below (molten solder temperature)
- Time — 10 seconds or less
- Number of times — One
- Flux — Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

(3) Cautions

- Fluxes

  Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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